

## Voltage Regulator

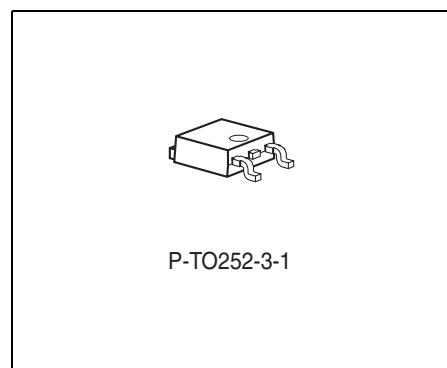
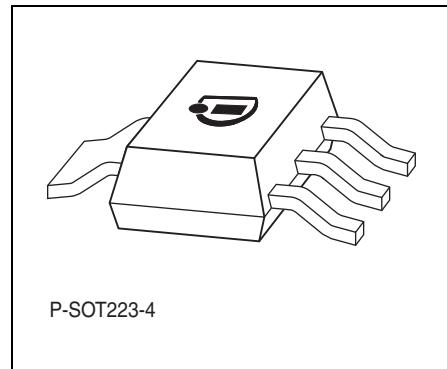
**TLE 4274 / 3.3V;2.5V**

### Features

- Output voltage: 3.3 V/2.5 V  $\pm$  4%
- Current capability 400 mA
- Very low current consumption
- Short-circuit proof
- Reverse polarity proof
- Suitable for use in automotive electronics

### Functional Description

The TLE 4274 / 3.3V;2.5V is a voltage regulator available in a SOT223 and TO252 package. The IC regulates an input voltage up to 40 V to  $V_{Q\text{rated}} = 3.3$  V/2.5 V. The maximum output current is 400 mA. The IC is short-circuit proof and has a shutdown circuit protecting it against overtemperature. The TLE 4274 is also available as 5 V, 8.5 V and 10 V version. Please refer to the data sheet TLE 4274.



### Dimensioning Information on External Components

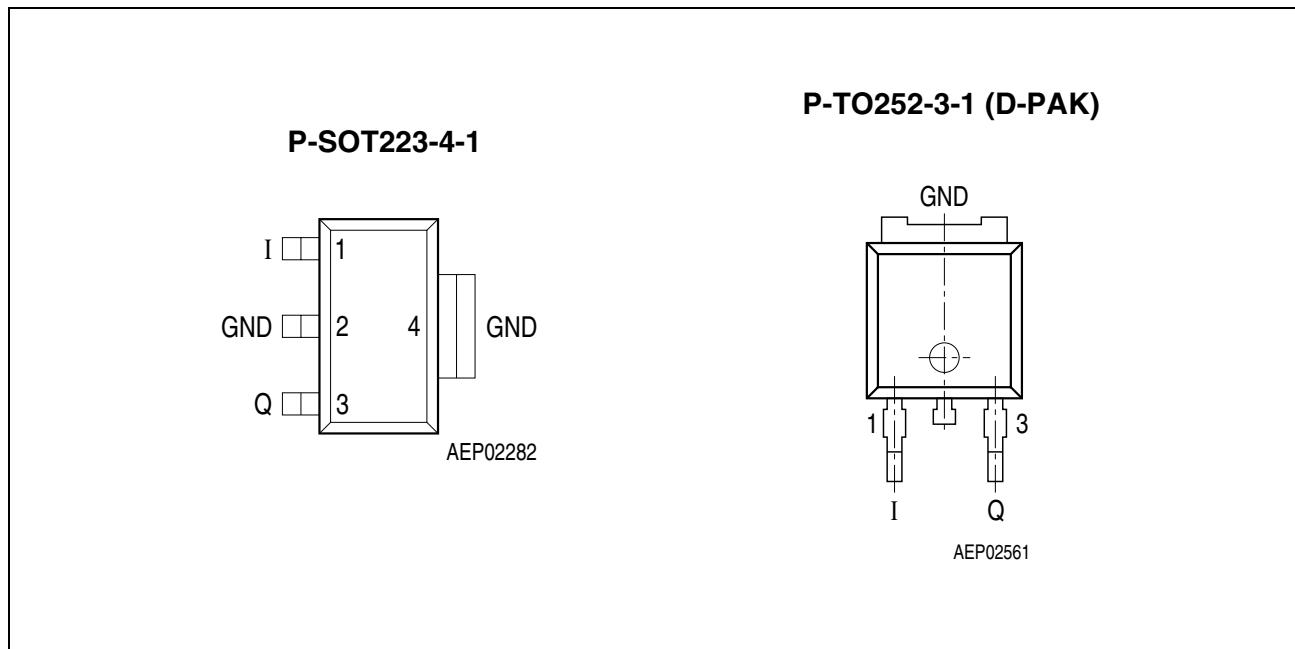
The input capacitor  $C_I$  is necessary for compensating line influences. Using a resistor of approx. 1  $\Omega$  in series with  $C_I$ , the oscillating of input inductivity and input capacitance can be damped. The output capacitor  $C_Q$  is necessary for the stability of the regulation circuit. Stability is guaranteed for capacities  $C_Q \geq 10 \mu\text{F}$  with an ESR of  $\leq 2.5 \Omega$  within the operating temperature range.

Type	Ordering Code	Package
TLE 4274 GSV33	Q67006-A9289	P-SOT223-4-1
TLE 4274 DV33	Q67006-A9348	P-TO252-3-1
TLE 4274 GSV25	Q67006-A9359	P-SOT223-4-1

## Circuit Description

The control amplifier compares a reference voltage to a voltage that is proportional to the output voltage and drives the base of the series transistor via a buffer. Saturation control as a function of the load current prevents any oversaturation of the power element. The IC also includes a number of internal circuits for protection against:

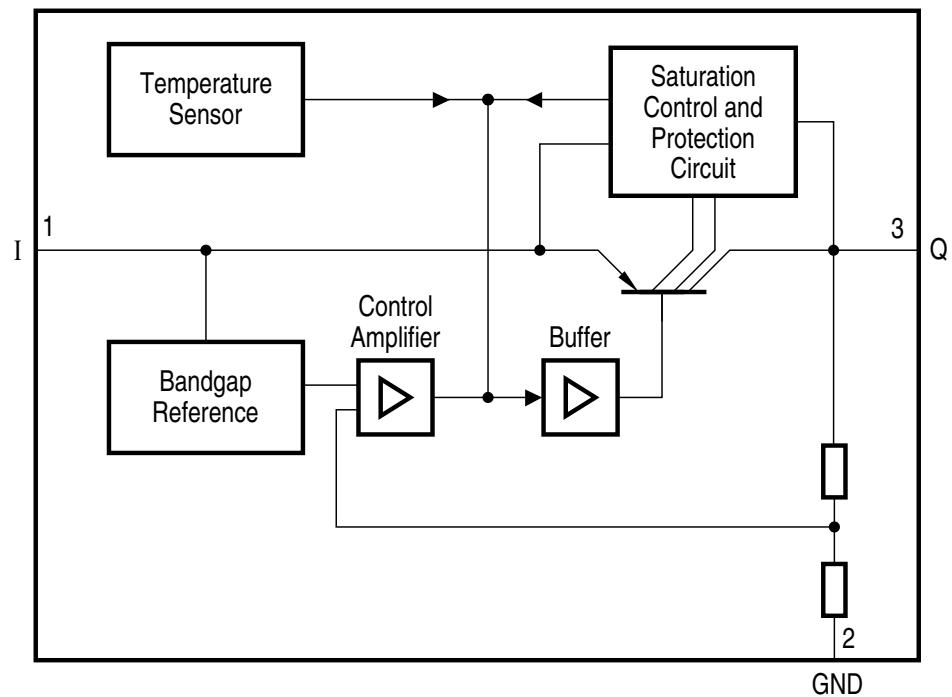
- Overload
- Overtemperature
- Reverse polarity



**Figure 1** Pin Configuration (top view)

**Table 1** Pin Definitions and Functions

Pin No.	Symbol	Function
1	I	<b>Input</b> ; block to ground directly at the IC with a ceramic capacitor.
2, 4	GND	<b>Ground</b> ; P-TO252-3-1: internally connected to heatsink
3	Q	<b>Output</b> ; block to ground with capacitor $C_Q \geq 10 \mu F$ , $ESR \leq 2.5 \Omega$



**Figure 2 Block Diagram**

**Table 2      Absolute Maximum Ratings**
 $T_j = -40$  to  $150$  °C

Parameter	Symbol	Limit Values		Unit	Test Condition
		Min.	Max.		
<b>Input</b>					
Voltage	$V_I$	-42	45	V	-
Current	$I_I$	-	-	-	Internally limited
<b>Output</b>					
Voltage	$V_Q$	-1.0	40	V	-
Current	$I_Q$	-	-	-	Internally limited
<b>Ground</b>					
Current	$I_{GND}$	-	100	mA	-
<b>Temperature</b>					
Junction temperature	$T_j$	-	150	°C	-
Storage temperature	$T_{stg}$	-50	150	°C	-

*Note: Maximum ratings are absolute ratings; exceeding any one of these values may cause irreversible damage to the integrated circuit.*

**Table 3      Operating Range**

Parameter	Symbol	Limit Values		Unit	Remarks
		Min.	Max.		
Input voltage	$V_I$	4.7	40	V	-
Junction temperature	$T_j$	-40	150	°C	-

**Thermal Resistance**

Junction ambient	$R_{thja}$	-	100	K/W	SOT223 <sup>1)</sup>
Junction ambient	$R_{thja}$	-	70	K/W	TO252 <sup>2)</sup>
Junction case	$R_{thjc}$	-	25	K/W	SOT223
Junction case	$R_{thjc}$	-	4	K/W	TO252

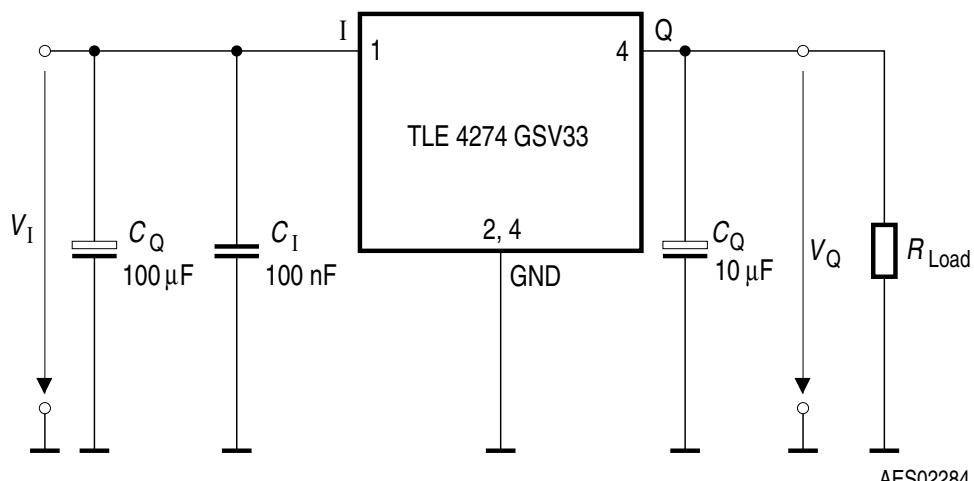
1) Soldered in, 1 cm<sup>2</sup> copper area at pin 4, FR4

2) Soldered in, minimal footprint, FR4

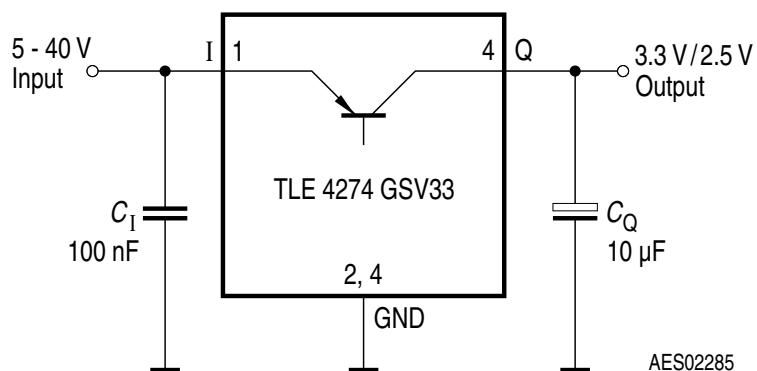
**Table 4 Characteristics**
 $V_I = 6 \text{ V}$ ;  $-40^\circ\text{C} < T_j < 150^\circ\text{C}$  (unless otherwise specified)

<b>Parameter</b>	<b>Symbol</b>	<b>Limit Values</b>			<b>Unit</b>	<b>Measuring Condition</b>
		<b>Min.</b>	<b>Typ.</b>	<b>Max.</b>		
Output voltage V33-Version	$V_Q$	3.17	3.3	3.44	V	$5 \text{ mA} < I_Q < 400 \text{ mA}$ $4.7 \text{ V} < V_I < 28 \text{ V}$
Output voltage V33-Version	$V_Q$	3.17	3.3	3.44	V	$5 \text{ mA} < I_Q < 200 \text{ mA}$ $4.7 \text{ V} < V_I < 40 \text{ V}$
Output voltage V25-Version	$V_Q$	2.4	2.5	2.6	V	$5 \text{ mA} < I_Q < 400 \text{ mA}$ $4.7 \text{ V} < V_I < 28 \text{ V}$
Output voltage V25-Version	$V_Q$	2.4	2.5	2.6	V	$5 \text{ mA} < I_Q < 200 \text{ mA}$ $4.7 \text{ V} < V_I < 40 \text{ V}$
Output current limitation <sup>1)</sup>	$I_Q$	400	600	—	mA	—
Current consumption; $I_q = I_I - I_Q$	$I_q$	—	100	220	μA	$I_Q = 1 \text{ mA}$
Current consumption; $I_q = I_I - I_Q$	$I_q$	—	8	15	mA	$I_Q = 250 \text{ mA}$
Current consumption; $I_q = I_I - I_Q$	$I_q$	—	20	30	mA	$I_Q = 400 \text{ mA}$
Drop voltage <sup>1)</sup> V33-Version	$V_{dr}$	—	0.7	1.2	V	$I_Q = 300 \text{ mA}$ $V_{dr} = V_I - V_Q$
Drop voltage <sup>1)</sup> V25-Version	$V_{dr}$	—	1.0	2.0	V	$I_Q = 300 \text{ mA}$ $V_{dr} = V_I - V_Q$
Load regulation	$\Delta V_Q$	—	40	70	mV	$I_Q = 5 \text{ mA} \text{ to } 300 \text{ mA};$ $V_I = 6 \text{ V}$
Line regulation	$\Delta V_Q$	—	10	25	mV	$\Delta V_I = 12 \text{ V} \text{ to } 32 \text{ V}$ $I_Q = 5 \text{ mA}$
Power supply ripple rejection	$PSRR$	—	60	—	dB	$f_r = 100 \text{ Hz};$ $V_r = 0.5 \text{ Vpp}$
Temperature output voltage drift	$dV_Q/dT$	—	0.5	—	mV/K	—

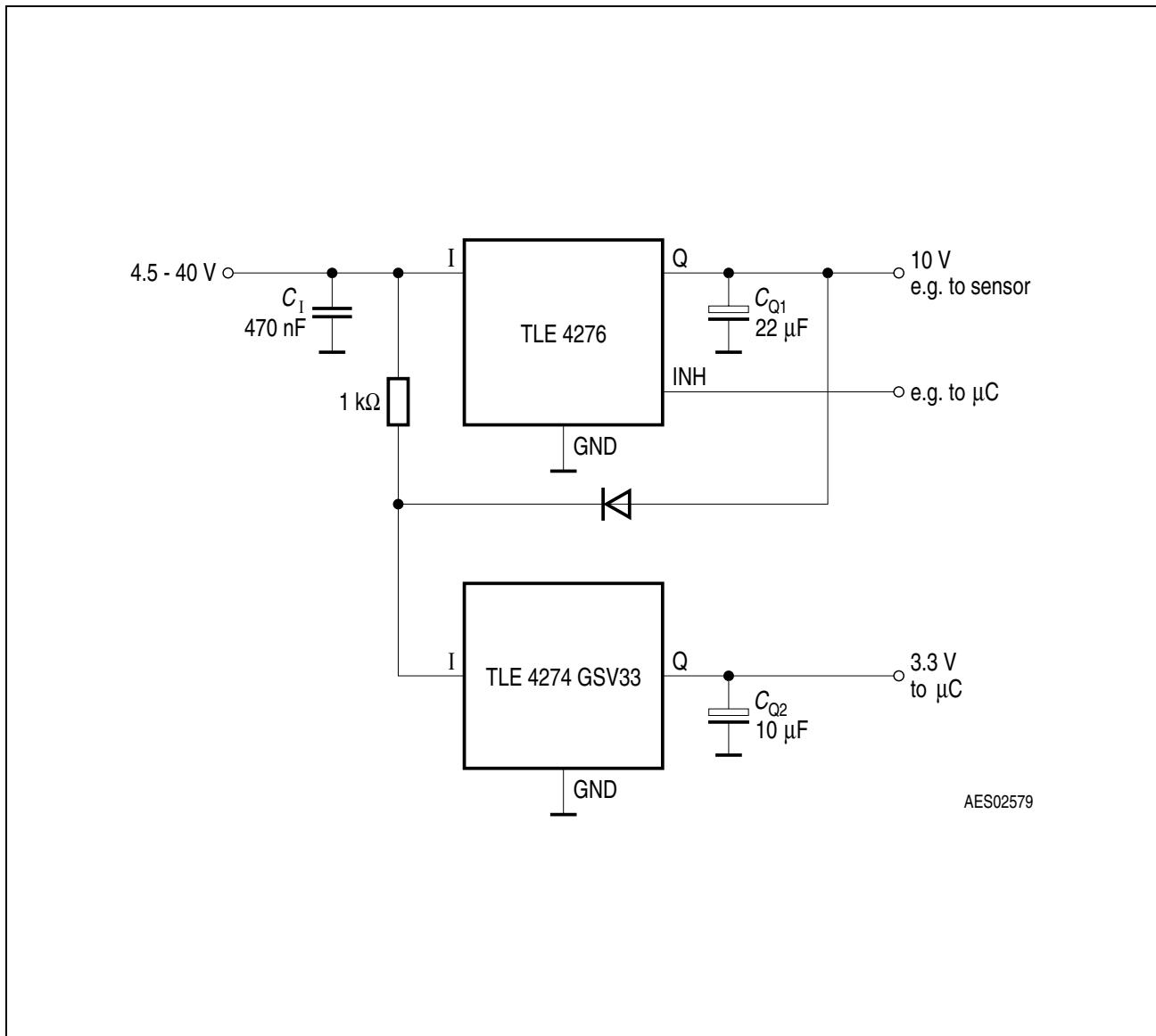
<sup>1)</sup> Measured when the output voltage  $V_Q$  has dropped 100 mV from the nominal value obtained at  $V_I = 6 \text{ V}$ .



**Figure 3 Measuring Circuit**



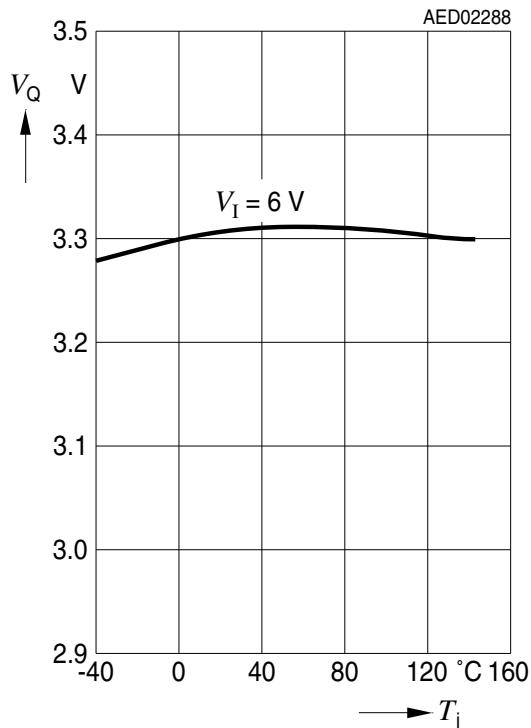
**Figure 4 Application Circuit**



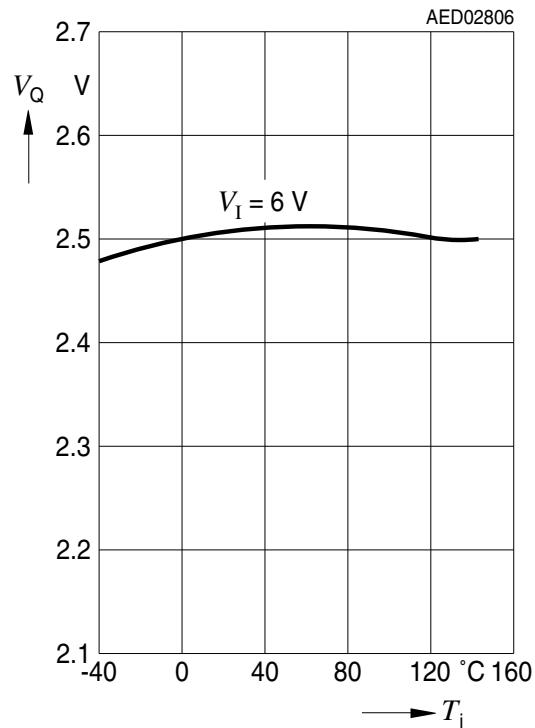
**Figure 5 Application Example**

## Typical Performance Characteristics

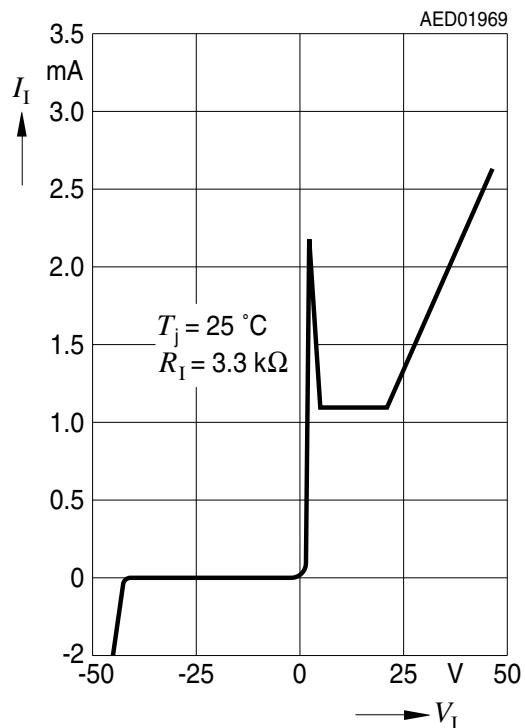
**Output Voltage  $V_Q$  versus  
Junction Temperature  $T_j$  (V33-Version)**



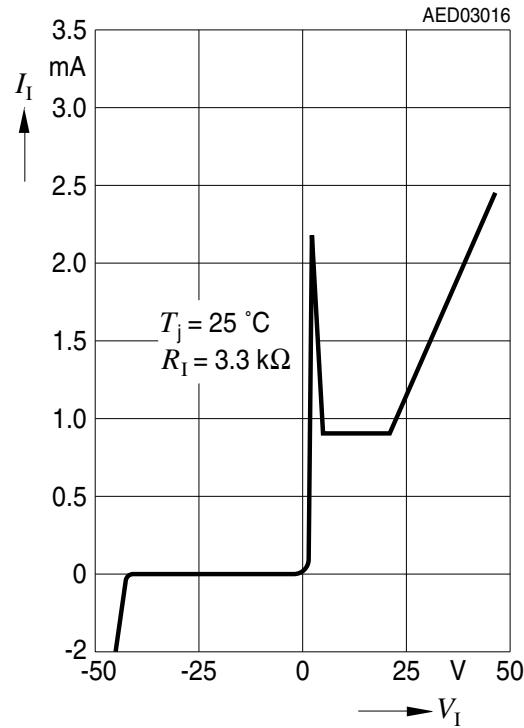
**Output Voltage  $V_Q$  versus  
Junction Temperature  $T_j$  (V25-Version)**



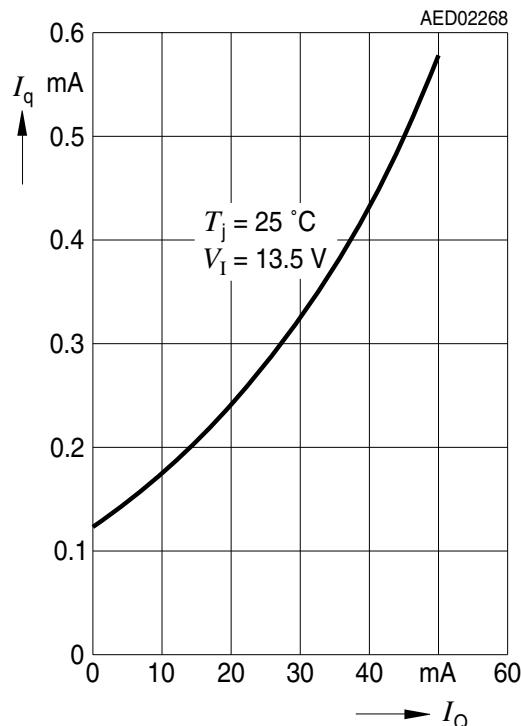
**Input Current  $I_I$  versus  
Input Voltage  $V_I$  (V33-Version)**



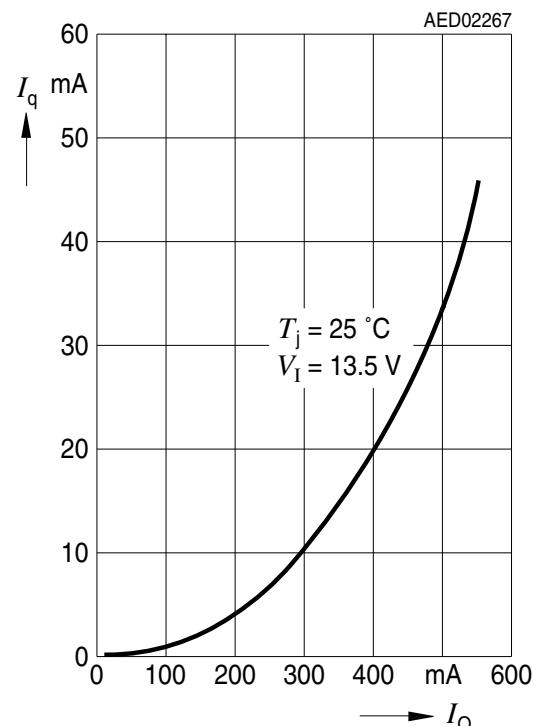
**Input Current  $I_I$  versus  
Input Voltage  $V_I$  (V25-Version)**



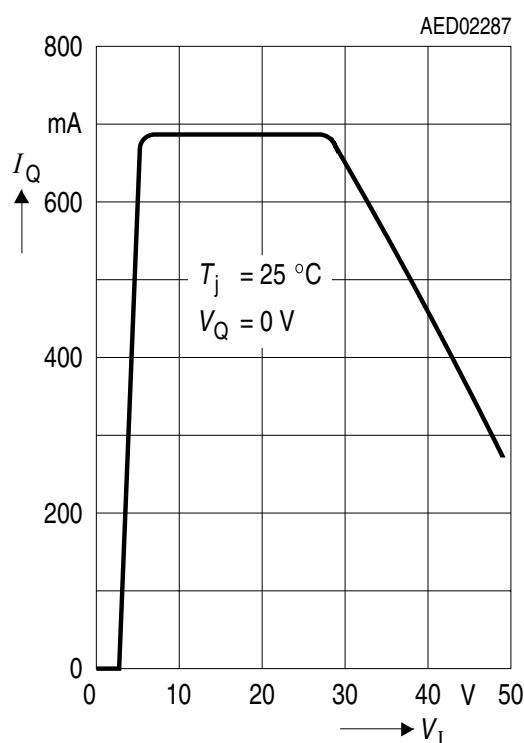
**Current Consumption  $I_q$  versus  
Output Current  $I_Q$  (low load)**



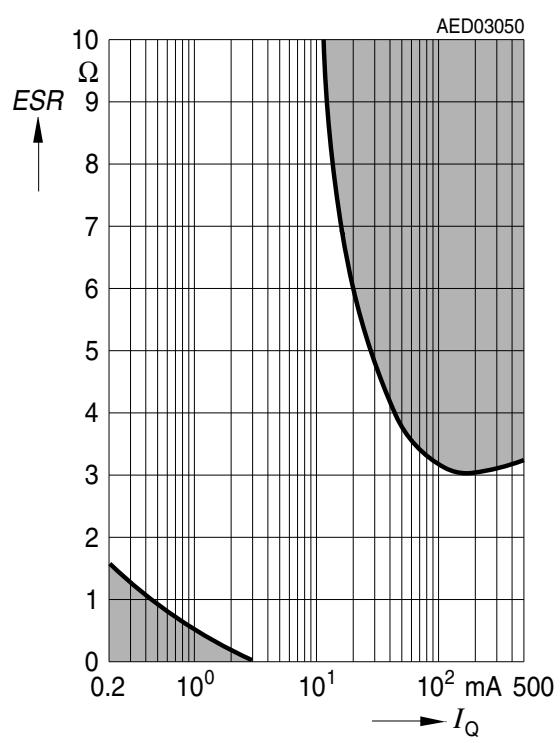
**Current Consumption  $I_q$  versus  
Output Current  $I_Q$  (high load)**



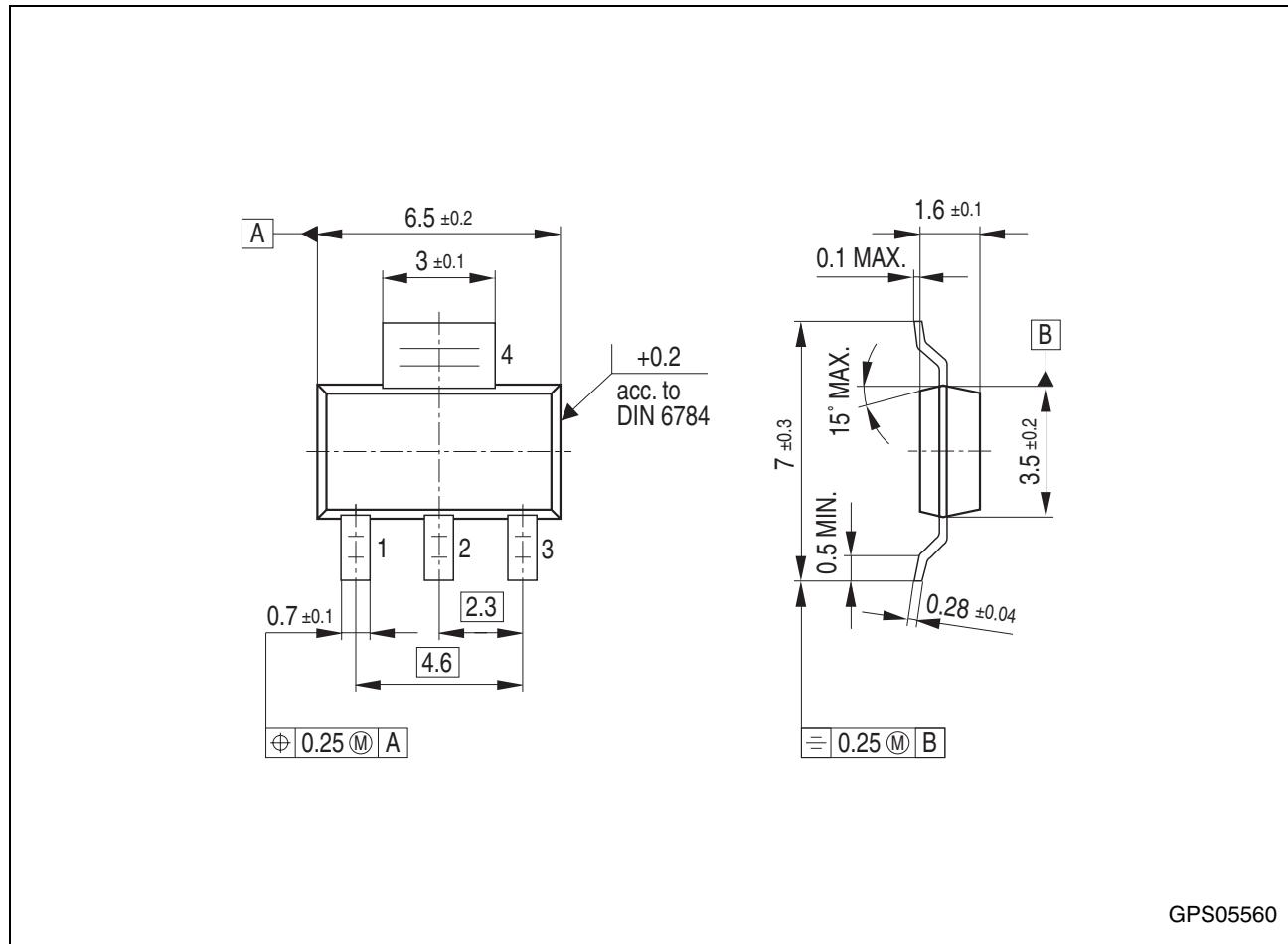
**Output Current  $I_Q$  versus  
Input Voltage  $V_I$**



**Region of Stability  
for  $C_Q = 10\text{ }\mu\text{F}$**



## Package Outlines

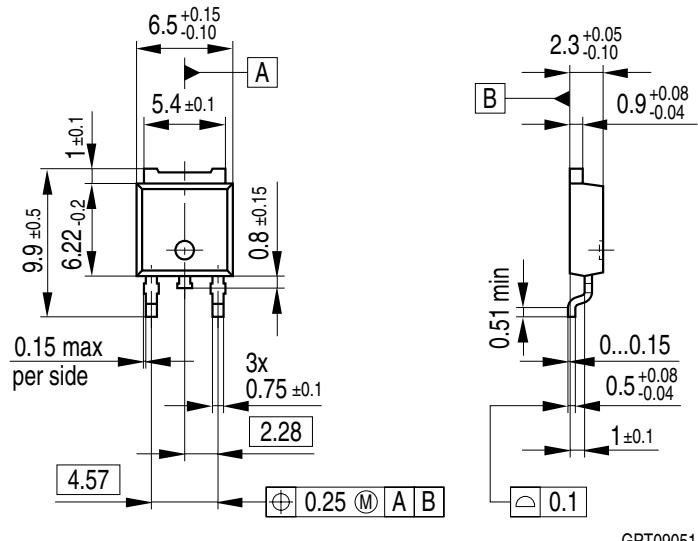


**Figure 6 P-SOT223-4-1 (Plastic Small Outline Transistor)**

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**SMD = Surface Mounted Device**

Dimensions in mm



**Figure 7 P-TO252-3-1 (Plastic Transistor Single Outline)**

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SMD = Surface Mounted Device

Dimensions in mm

**Edition 2004-01-01**

**Published by Infineon Technologies AG,  
St.-Martin-Strasse 53,  
81669 München, Germany**

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